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Inducing a many-body topological state of matter through Coulomb-engineered local interactions

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The engineering of artificial systems hosting topological excitations is at the heart of current condensed matter research. Most of these efforts focus on single-particle properties, neglecting possible engineering routes via the modifications of the fundamental many-body interactions. Interestingly, recent experimental breakthroughs have shown that Coulomb interactions can be efficiently controlled by substrate screening engineering. Inspired by this success, we propose a simple platform in which topologically nontrivial many-body excitations emerge solely from dielectrically engineered Coulomb interactions in an otherwise topologically trivial single-particle band structure. Furthermore, by performing a realistic microscopic modeling of screening engineering, we demonstrate how our proposal can be realized in one-dimensional systems such as quantum-dot chains. Our results put forward Coulomb engineering as a powerful tool to create topological excitations, with potential applications in a variety of solid-state platforms.

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I. INTRODUCTION

Topology represents one of the most fertile fields in modern condensed matter physics [1–3], boosted by the prediction and experimental realization of topological systems, ranging from quantum spin Hall [4] and Chern [5,6] insulators to topological superconductors [7–9] and topological crystalline insulators [10,11]. Besides being of fundamental interest, these states are widely discussed due to their potential impact on solid-state technology, including low-consumption electronics [12], spintronics [13], and topological quantum computing [14]. The topological classification of noninteracting systems continues to grow with the recent examples of higher-order topological insulators [15,16], non-Hermitian topology [17–19], fragile topological phases [20,21], quasiperiodic topology [22,23], and random topological systems [24,25].

Some of the most groundbreaking discoveries in condensed matter physics have been intimately related with strong interactions, with the paradigmatic examples of high-temperature superconductivity [26] and fractional quantum Hall physics [27,28]. It is thus not surprising that the interplay of topology and correlation effects is increasing as one of the most enigmatic fields in modern condensed matter physics. Topological states associated with interactions in topological Mott [29] and Kondo [30,31] insulators represent examples.

In many instances, the role of interactions in generating topology is, however, reduced to a mean-field single-particle effect [29–32]. The potentially genuine role of interactions in topological systems beyond mean-field single-particle effects is, hence, still at an early stage.

Here, we demonstrate that Coulomb-engineered local interactions allow us to induce many-body topological excitations. Our mechanism puts forward a paradigm to generate topological states purely driven by electronic interactions. These topological states result from imprinting quasiperiodic structures to the local Coulomb interactions \( U_n \) only, without requiring modifications to the topologically trivial single-particle dispersions. Crucially, we show how such a spatial structuring of the local interactions can be experimentally achieved using quantum-dot (QD) arrays and by exploiting Coulomb engineering [33–36] via structured substrate, as depicted in Figs. 1(a) and 1(b). This paper is organized as follows: In Sec. II, we present how spatially modulated Coulomb interactions give rise to topological modes at the mean-field level. In Sec. III, we show how topological modes appear from these Coulomb interactions in a purely many-body model without a single-particle analog. In Sec. IV, we show how modulated Coulomb interactions can be realized by dielectric engineering. Finally, in Sec. V, we summarize our conclusions.

II. SCREENING-INDUCED SINGLE-PARTICLE TOPOLOGY

To exemplify our proposal using a simple Hamiltonian, we start with a model in which interactions generate a topological state that can be understood on the single-particle level within a mean-field framework. We consider a linear array of QDs with a single level per dot and spatially modulated local Coulomb interactions. The corresponding Hamiltonian

\[
H = \sum_n \left( \epsilon_n c_n^\dagger c_n + U_n c_n^\dagger c_n c_{n+1} c_{n+1}^\dagger \right) + \text{H.c.}
\]
reads

$$H = \sum_{n,s} t \hat{c}_{n,s}^\dagger \hat{c}_{n+1,s} \lambda + \sum_n U_n \sigma_{n,\uparrow} \sigma_{n,\downarrow} + \sum_n \widetilde{U}_n \sigma_{n,\uparrow} \bar{\sigma}_{n,\downarrow} + \text{H.c.}$$  \hspace{1cm} (1)$$

where $n$ is the QD site index, $t$ the nearest-neighbor hopping, and $U_n$ a spatially varying local Coulomb repulsion of the form $U_n = \widetilde{U}[1 + \lambda \cos(\Omega n + \phi)]$, which is periodically modulated around a constant $\widetilde{U}$. Here, $\Omega$, $\phi$, and $\lambda$ are the modulation wavelength, phase, and strength, respectively, which can be efficiently controlled via spatially structured substrates, as we demonstrate later. With these parameters, we are able to explore the full phase space of Coulomb pattern-induced topological effects. We solve this model via a mean-field decoupling yielding $H_{\text{mf}} = \sum_{n,s} t \hat{c}_{n,s}^\dagger \hat{c}_{n+1,s} \lambda + \sum_n U_n \sigma_{n,\uparrow} \sigma_{n,\downarrow} + \text{H.c.}$. Assuming time reversal symmetry, i.e., $\sigma_{n,\uparrow} \sigma_{n,\downarrow} = \sigma_{n,\downarrow} \sigma_{n,\uparrow}$, the interactions $U_n$ locally renormalize the onsite energies, following the modulation profile. This mean-field Hamiltonian is a realization of a diagonal Aubry-Andre-Harper model [37,38] for electrons with a nonzero charge average per site that is known to have edge states stemming from a parent two-dimensional (2D) Hall state [39,40].

The topological invariant at certain excitation gaps of such models is given by the Chern number [39–43], which matches the number of states that cross the gap as a function of the phason $\phi$ [40,44]. In Fig. 2(a), we show the bulk energy spectrum of a QD chain as a function of $\Omega$ at half-filling, which is clearly gapped in certain regions. As shown in Fig. 2(b), these gaps increase with $\widetilde{U}$. These gaps are of topological origin [43,45], as depicted in Figs. 2(c) and 2(d), where we show the mean-field spectrum as a function of $\phi$. In particular, we see two edge modes (red and blue) that cross the gap as $\phi$ is changed. Spatially modulated onsite Hubbard interactions are thus indeed capable of generating topological nontrivial modes by modulating the effective single-particle mean-field Hamiltonian. This rather simple mechanism on the effective single-particle level exemplifies that interactions alone are able to induce nontrivial topology.

### III. SCREENING-INDUCED MANY-BODY TOPOLOGY

In a more sophisticated scenario, we induce topological behavior in a regime with a topologically trivial mean-field Hamiltonian. To this end, we propose a similar interacting Hamiltonian as before but with exactly one electron per site:

$$H = \sum_{n,s} t \hat{c}_{n,s}^\dagger \hat{c}_{n+1,s} \lambda + \sum_n U_n \left( c_{n,\uparrow}^\dagger c_{n,\uparrow} - \frac{1}{2} \right)^{\gamma} \frac{1}{2} + \text{H.c.} \hspace{1cm} (2)$$

This Hamiltonian can be understood as a Hubbard QD chain in which each QD is biased so that it is half filled. The corresponding mean-field decoupled Hamiltonian is by construction uniform $H_{\text{mf}} = \sum_{n,s} t \hat{c}_{n,s}^\dagger \hat{c}_{n+1,s} \lambda + \text{H.c.}$ and thus topologically trivial. To exactly treat the Hamiltonian from Eq. 2, we use the tensor network formalism [46–52]. For all $\phi$, the system remains nonmagnetic and half filled in every site. We analyze the dynamical spin response defined by $S(\omega, n) = \langle \hat{G}_S \hat{S}_z (\omega - E_{\text{GS}}) \hat{S}_z \hat{G}_S \rangle$ that can be measured with inelastic spectroscopy [53] and which is shown in Figs. 3(a) and 3(c) as a function of $\phi$ for different $\Omega$. Again, we find edge excitations crossing bulk excitation gaps as the phason is changed. These finite spectral gaps are visible in the bulk spin responses shown in Figs. 3(b) and 3(d) and are present for arbitrary modulation frequencies $\Omega$, as depicted in Fig. 3(e), leading to in-gap edge excitations for generic $\Omega$. These gaps are furthermore proportional to the Hubbard...
modulation strength $\lambda$, as shown in Fig. 3(f). We verified that such in-gap modes are robust toward the presence of random disorder in the modulated local Coulomb interaction $U_n$ or interdot hopping $t$. These characteristics underline their topological origin [40,44,54], which is here solely created by modulated many-body interactions.

The model of Eq. 2 is a many-body version of the Aubry-Andre-Harper model, as introduced in the previous section. However, a mapping to the parent electronic 2D quantum Hall state cannot be performed due to its genuine many-body nature. To understand how the engineered interactions are capable of creating topological edge modes here, we explore the model in the strong coupling limit, i.e., $\bar{U} \gg t$. In this strongly interacting limit, spin and charge degrees of freedom are separated while every QD is still hosting one electron, giving rise to gaped charge excitations decoupled from the spin sector. This can be explicitly shown by performing a Schrieffer-Wolff transformation of the Hamiltonian from Eq. 2 (which is not possible for Eq. 1) into spin operators yielding the effective Hamiltonian

$$H_{\text{eff}} = \sum_n J_{n,n+1} S_n \cdot S_{n+1},$$

(3)

where $S_n$ are the $S = \frac{1}{2}$ operators on each site, and $J_{n,n+1}$ is the effective exchange interaction that takes the form $J_{n,n+1} = 2\lambda(\frac{1}{U_n} + \frac{1}{U_{n+1}}) \approx \frac{2\lambda^2}{U_n} [1 - \cos(\Omega n + \phi)]$ [55]. This Hamiltonian realizes a quasiperiodic antiferromagnetic $S = \frac{1}{2}$ Heisenberg model, [56,57] whose ground state is a time-reversal symmetric singlet state. Such a ground state is an entangled many-body state that cannot be described as a classical symmetry broken anti-ferromagnetic state due to strong quantum fluctuations. Its low-energy excitations have $S = \frac{1}{2}$, in contrast to $S = 1$ of classical magnets. A common approach to characterize these low-energy excitations is to use a so-called parton Abrikosov fermion transformation of the form $S_n^\sigma = \sum_{\alpha,s} \frac{1}{4} \tilde{\alpha}^\sigma_{s}\tilde{f}_{n,s}\tilde{f}_{n,s}^\dagger$, where $f_{n,s}^\dagger$ and $f_{n,s}$ are the creation and annihilation spinon operators [58]. Using this to transform the operators in $H_{\text{eff}}$ followed by a mean-field decoupling for the Abrikosov fermions, we obtain an effective Hamiltonian of the form $H_{n}^{\text{eff}} = \sum_{n,s} \gamma_{n,n+1} f_{n,s}^\dagger f_{n+1,s} + H.c.$ [59]. This effective Hamiltonian $H_{n}^{\text{eff}}$ describes fractionalized particles with $S = \frac{1}{2}$ and no charge, where the effective hoppings are proportional to the exchange coupling of the parent Heisenberg model, i.e., $\gamma_{n,n+1} \sim J_{n,n+1}$. Here, $H_{n}^{\text{eff}}$ thus again resembles an off-diagonal spinon Aubry-Andre-Harper model that can be mapped to a 2D quantum Hall state for spinons. As a result, the effective Hamiltonian $H_{\text{eff}}$ hosts topologically nontrivial edge spin excitations, and so does the original Hamiltonian from Eq. 2 in the strong-coupling limit, resulting from the spatially patterned local interactions. The topological behavior of the model from Eq. 2 is thus clearly induced by many-body effects alone and does not rely on any topological behavior on the single-particle or mean-field level.

Let us now briefly comment on the role of edge perturbations. A perturbation on the edge can change the energy of the edge mode discussed above, as in the single-particle Su-Schrieffer-Heeger (SSH) model [60–62], in second-order topological insulators [15,63–65], as well as in topological crystalline insulators [10,66]. In fact, the topologically nontrivial states of the SSH and higher-order topological models can be rationalized as highly specific examples of a generalized single-particle quasi-periodic topological mode [43]. In this regard, the topological origin of the modes in our many-body proposal share analogous robustness with the modes in the SSH [60–62] and higher-order models [15,63–65]. Finally, it is worth noting that, in the presence of an edge perturbation, the spectrum of the presented many-body models will always show an edge mode pumping the gap as the parameter $\phi$ is changed [40,42,43,67].

IV. LOCAL COULOMB ENGINEERING

After establishing the novel concept of Coulomb-engineered topology in one-dimensional (1D) systems, we now turn to the experimental feasibility. While 1D tight-binding-like chains have been already created and studied using metallic nanospheres [68,69], QDs [70,71], and even single atoms [72,73], spatially patterned Hubbard models have not been created yet. Thus, we will focus in the following on how a structuring of $U_n$ can be achieved using substrate-screening effects.

FIG. 3. Screening-induced many-body topology. Spin spectral function (a) in the edge and (b) in the bulk for $\Omega = \pi/\sqrt{3}$. Spectral function (c) in the edge and (d) in the bulk for $\Omega = \pi/2$. (e) Bulk spectral function as a function of $\Omega$, showing gaps at generic values of $\Omega$. (f) Approximate linear scaling of the topological gap as a function of $\lambda$. We used 30 sites and set $\lambda = 0.5$, $\bar{U} = 6t$, and $\Omega = 0.4\pi$ if not stated otherwise.
The local Coulomb interactions used in the Hubbard models from above are matrix elements evaluated in a single-orbital Wannier basis \( \psi(r) \) given by \( U_n = \int dr dr' |\psi(r-r)|^2 |\psi(r'-r)|^2 U(r,r') \). In the following, we will approximate these elements by \( U_n \approx e\Phi_n(\delta) \), where \( \Phi_n(\delta) \) is the electrostatic potential of an electron with charge \( e \) localized at the lattice position \( n \) as felt by a second electron in its close vicinity (at distance \( \delta \)), as depicted in Fig. 4(a). The screening effects of a homogeneous substrate can readily be calculated using the concept of image charges, as described in the Methods section. Here, \( U_n^{\text{hom}} \) is then fully defined by the effective Wannier-orbital spread \( \delta \) and the dot-substrate separation \( h \), as depicted in Fig. 4(a) for different \( \delta \) and \( h \) as a function of the substrate screening constant \( \varepsilon_{\text{sub}} \) and for a background \( \varepsilon_0 = 2 \). The unscreened (bare) value of the local Coulomb interaction is defined by \( \delta \), whereas \( h \) controls its vulnerability to \( \varepsilon_{\text{sub}} \) [74]. We see that the local Coulomb interaction can be significantly modulated by changes to the homogeneous substrate screening.

The key element of our Coulomb-engineered topology proposal is a spatial modulation of the local interactions \( U_n \). To achieve this, we propose to spatially structure the substrate screening. A corresponding heterogeneous setup with just one dielectric interface in the substrate is depicted in Fig. 4(b). Here, we approximate the resulting potential \( \Phi(\delta) \) with a multi-image-charge ansatz to fulfill the necessary boundary conditions (see Methods for more details). Figure 4(b) shows a corresponding example in the form of \( U^{\text{het}}(\varepsilon_{\text{sub}}, \varepsilon_{\text{sub}}^R) \) for \( \delta/h = 1 \) [75]. We present data for \( \varepsilon_{\text{sub}}^{L} = \varepsilon_{\text{sub}}^{R} \) (homogeneous substrate), \( \varepsilon_{\text{sub}}^R = 2 \), and \( \varepsilon_{\text{sub}}^R = 10 \), from which we see that the homogeneous solution smoothly interpolates between the two heterogeneous situations for \( \varepsilon_{\text{sub}}^{L} \in [2, 10] \). Here, \( U^{\text{het}}(\varepsilon_{\text{sub}}^{L}, \varepsilon_{\text{sub}}^{R} = 2) \) is always the largest due to the reduced screening from the right side of the substrate, while \( U^{\text{het}}(\varepsilon_{\text{sub}}^{L}, \varepsilon_{\text{sub}}^{R} = 10) \) is the smallest for \( \varepsilon_{\text{sub}}^{L} \in [2, 10] \). Most importantly, we find that there are just minor quantitative changes to the local Coulomb interaction screened by \( \varepsilon_{\text{sub}}^{L} \) with \( \varepsilon_{\text{sub}}^{R} \) being different in close vicinity. We can thus conclude that periodically patterned substrate screening functions with additional dielectric interfaces will not qualitatively affect the local substrate screening properties from the immediate surrounding.

As described above and shown in Fig. 3(f), the topological gap in the spin spectral function is proportional to \( t^2 \lambda / \bar{U} \). The Coulomb modulation strength \( \lambda \) thus plays a significant role for our proposal, as it maximizes the topological gap and thus protects the topological character of the system. To estimate the maximal possible modulation strength, we define \( \lambda_{\text{max}} = U_{\text{max}}^{\text{hom}} / U_{\text{max}}^{\text{het}} \) with \( U_{\text{max}} = U_{\text{max}} - U_{\text{min}} \) and \( U_{\text{ave}} = (U_{\text{max}} + U_{\text{min}}) / 2 \), i.e., \( \lambda_{\text{max}} \) is defined by the the maximally and minimally achievable local interactions. For the homo-geneous substrate, we can calculate \( \lambda_{\text{hom}} \) by defining \( U_{\text{max}}^{\text{hom}} = U_{\text{ave}}^{\text{hom}}(\varepsilon_{\text{min}}) \) and \( U_{\text{min}}^{\text{hom}} = U_{\text{ave}}^{\text{hom}}(\varepsilon_{\text{max}}) \) with \( \varepsilon_{\text{min}} < \varepsilon_{\text{max}} \). In Fig. 4(c), we show the resulting values for fixed \( \varepsilon_{\text{min}} = 3 \). Here, \( \lambda_{\text{hom}}^{\text{max}} \) steadily increases with the dielectric contrast \( \Delta \epsilon \), which is driven by the enhancement of \( \Delta \epsilon \) (due to the reduction of \( U_{\text{min}} \)) upon increasing \( \varepsilon_{\text{max}} \). Additionally, \( \lambda_{\text{hom}}^{\text{max}} \) increases with the \( \delta/h \) ratio, which results from a decreased \( U_{\text{ave}} \) for increased \( \delta \) and the enhanced substrate-screening vulnerability of \( U^{\text{het}} \) upon decreasing \( h \). Here, \( \lambda_{\text{hom}}^{\text{max}} \) is thus maximized by large dielectric contrasts and large \( \delta/h \) ratios.

These homogeneous \( \lambda_{\text{hom}}^{\text{max}} \) are, however, just upper limits. In a more realistic setting, \( U_{\text{max}} \) and \( U_{\text{min}} \) might result from a heterogeneous substrate with additional dielectric interfaces, as depicted in the sketch of Figs. 4(e) and 4(f). To estimate \( \lambda_{\text{het}}^{\text{max}} \) in such a setting, we imagine the transition from \( U_{\text{max}} \) to \( U_{\text{min}} \) taking place within three lattice sites and set \( U_{\text{max}}^{\text{het}} = U_{\text{ave}}^{\text{het}}(\varepsilon_{\text{min}}) \) and \( U_{\text{min}}^{\text{het}} = U_{\text{ave}}^{\text{het}}(\varepsilon_{\text{max}} + \Delta \epsilon) \) with \( \varepsilon_{\text{mid}} = \varepsilon_{\text{min}} + \Delta \epsilon / 2 \). The resulting values are shown in Fig. 4(d). Due to the additional dielectric interface in the substrate, \( \Delta \epsilon \) is decreased so that \( \lambda_{\text{het}}^{\text{max}} \) is overall smaller than \( \lambda_{\text{hom}} \), but behaves otherwise similar. For \( \delta = 2 \AA \) (orange and red dots) \( \lambda_{\text{het}}^{\text{max}} \) represents the lower limit since the interface is positioned here at \( \varepsilon_0 = 2 \AA \). By increasing \( \varepsilon_0 \), \( \lambda_{\text{het}}^{\text{max}} \) approaches the upper limit \( \lambda_{\text{het}}^{\text{max}} \). The optimal parameter regime to realize screening-induced many-body topology is thus defined by small QD heights \( h \), large QD diameters \( \delta \), large...
QD separations $y_0$, and large dielectric contrasts $\Delta_\varepsilon$, which increases $\lambda_{\text{max}}$ and thus the topological gap.

V. CONCLUSIONS

We proposed a family of topological states whose topological excitations stem purely from many-body interactions instead of from single-particle engineering. Our proposal compares with conventional schemes that rely on engineering single-particle physics, demonstrating that engineered electronic interactions are a powerful complementary tool for exploring quantum states, which can be also used to create more complex models, such as second-order topological insulators [15,43,64]. Importantly, we showed that Coulomb engineering can be efficiently utilized to create the needed interaction profiles, demonstrating that our proposal can be implemented with current dielectric-engineering techniques. Our results thus put forward a method to create topological interaction profiles, demonstrating that our proposal can be efficiently utilized to create the needed engineering can be efficiently computed using a recursion relation for the many-body Hamiltonian of Eq.2. In particular, we explore two different to be robust against perturbations of the many-body Hamiltonian of Eq. 2, where $\lambda_0$ and $\Delta_\varepsilon$ are site-dependent random numbers. We show in Fig. 5(b) the spectral function at the edge, including this onsite Coulomb disorder present in the experimental setup. This potential needs to solve the Poisson equation in each $\varepsilon_i$ region, i.e.,

\[
\Delta \Phi(\vec{x}) = \frac{\rho(\vec{x})}{\varepsilon_0} \quad \text{for } y \geq 0,
\]

\[
\frac{\partial \Phi(\vec{x})}{\partial y} = \varepsilon_{\text{sub}} \frac{\partial \Phi(\vec{x}_y)}{\partial y}, \quad \text{for } y < 0,
\]

where $\rho(\vec{x})$ is the point-charge density of the source charge $q_{\text{00}}$ and must fulfill the boundary conditions

\[
\Phi(\vec{x}_y) = \Phi(\vec{x}_{y-}),
\]

\[
\varepsilon_0 \frac{\partial \Phi(\vec{x}_y)}{\partial y} = \varepsilon_{\text{sub}} \frac{\partial \Phi(\vec{x}_{y-})}{\partial y},
\]
Thus, in the case of a homogeneous substrate, the influence of the charge at the dielectric interface defined by \( y = 0 \) can be readily fixed by the boundary conditions yielding
\[
q_{01} = \frac{\epsilon_0 - \epsilon_{\text{sub}}}{\epsilon_0 + \epsilon_{\text{sub}}} q_{00},
\]
and
\[
q_{11} = q_{01} - q_{00}.
\]

Thus, in the case of a homogeneous substrate, the influence of \( \epsilon_{\text{sub}} \) to the local Coulomb interaction \( U_n \) can be calculated analytically. As soon as there is an additional dielectric interface in the substrate, we cannot find an analytic solution anymore. To estimate the impact of this heterogeneous substrate screening, we construct an approximate solution from a multiple image charge ansatz of the form
\[
\Phi(\vec{x}) = \begin{cases} 
\frac{1}{\epsilon_0} \frac{q_{00}}{|\vec{x} - \vec{0}_0|}, & y \geq 0 \\
\frac{1}{\epsilon_0} \sum_{i=0}^{2N} \frac{q_{00}}{|\vec{x} - \vec{0}_i|}, & y < 0, x \leq 0, \\
\frac{1}{\epsilon_{\text{sub}}} \sum_{i=0}^{N} \frac{q_{00}}{|\vec{x} - \vec{0}_i|}, & y < 0, x > 0
\end{cases}
\]
which is supposed to solve the Poisson equation given in Eq. (C2) with the boundary conditions at the \( y = 0 \) interfaces
\[
\Phi(\vec{x}_{y=0}) = \Phi(\vec{x}_{y=0}), \quad y = 0,
\]
\[
\frac{\partial \Phi(\vec{x}_{y=0})}{\partial y} = \frac{\epsilon_{\text{sub}}}{\epsilon_{\text{sub}}}, \quad y = 0, x \leq 0,
\]
\[
\frac{\partial \Phi(\vec{x}_{y=0})}{\partial y} = \frac{\epsilon_0}{\epsilon_{\text{sub}}}, \quad y = 0, x > 0,
\]
and at the \( x = 0 \) interface in the substrate
\[
\Phi(\vec{x}_{x=0}) = \Phi(\vec{x}_{y=0}), \quad y < 0, x = 0,
\]
\[
\frac{\partial \Phi(\vec{x}_{x=0})}{\partial x} = \frac{\epsilon_{\text{sub}}}{\epsilon_{\text{sub}}}, \quad y < 0, x = 0.
\]

If we fix all image charge positions, we can use the \( 4N \) image charges \( q_{0(1,2)\mu} \) to fulfill \( 4N \) boundary conditions at discrete interface positions \( x_i \). The resulting linear equation system is well defined and has a unique solution. Here, however, we reformulate the Poisson equation into a minimization problem of the form
\[
\min_{q_{0(1,2)\mu}} \left[ \frac{\Delta \Phi(\vec{x}) - \epsilon_{\text{sub}}}{\epsilon_0} \right]_{y > 0}, \quad \left[ \frac{\Delta \Phi(\vec{x}) - \epsilon_{\text{sub}}}{\epsilon_0} \right]_{y < 0}
\]
using the boundary conditions from Eqs. (C8)–(C12) to define constraints for the minimization. This relaxes the one-to-one correspondence between the number of image charges and the number of discrete boundary conditions.

Numerically, we use the Sequential Least SQuares Programming (SLSQP) algorithm [78] as implemented in the Scipy minimization package. We use \( 5 \times 2 \times 5 \) image charges per substrate region (i.e., 100 in total), separated by \( (d_x, d_y, d_z) = (4, 4, 4) \text{ Å} \) and distributed, as indicated in Fig. 6, and 182 boundary condition points at the \( y = 0 \) interface and 130 points at the \( x = 0 \) interface distributed, as also indicated in Fig. 6. To minimize the function defined in Eq. (C13), we investigate the Poisson equation on a discrete grid of 18 points in the \( x-z \) plane slightly below the source charge (see Fig. 6). The source charge is positioned at \( \vec{q}_{00} = (h, y_0 = -2, 0) \) (with variable distance \( h \) to the \( y = 0 \) interface and fixed position relative to the vertical interface in the substrate), and its charge distribution is approximated using a three-dimensional Gauss function of the form
\[
\rho(\vec{x}) = \frac{q_{00}}{\sigma^3 (2\pi)^{1/2}} \exp \left[ -\frac{(\vec{q}_{00} - \vec{x})^2}{\sigma^2} \right],
\]
with \( \sigma = 0.15 \text{ Å} \). Finally, \( U_n = e\Phi(\vec{\delta}) \) is evaluated using \( e\Phi_{00} \approx 14.39 \text{ eV Å} \) and \( \vec{\delta} = \vec{q}_{00} + (\delta, 0, 0) \) with variable \( \delta \).

In Fig. 6, we show a corresponding example result for \( \epsilon_0 = 2, \epsilon_{\text{sub}} = 4, \epsilon_{\text{sub}} = 10, h = 2 \text{ Å} \), and \( \delta = |y_0| = 2 \text{ Å} \). This situation, we would a priori expect to see equipotential lines with small kinks at the \( \epsilon_0/\epsilon_{\text{sub}} \) boundary and with enhanced kinks at the interfaces to the \( \epsilon_{\text{sub}} \) area, which is approximately the case in our numerical estimate. Furthermore, we see that these boundary conditions are also approximately fulfilled between the discrete boundary positions in the vicinity of the
source charge (large red dot). Further away, we however also find deviations to this. We thus expect our numerical solution to be approximately valid in the vicinity of the source charge, which is enough to estimate the local Coulomb interaction.


[53] We take $\Delta \ll 1$ and $\Omega \ll 1$.


[56] We take $\Delta \ll 1$ and $\Omega \ll 1$.


[59] We assume in the mean-field ansatz that time reversal symmetry is not broken and that no anomalous terms are generated, as will be expected for the uniform Heisenberg model.


[74] Systems with a small Wannier-orbital spread $\delta$ have large local Coulomb interactions, and systems with small effective heights $h$ are more strongly affected by the substrate.
We assume the location of the source charge above $\epsilon_{\text{sub}}^L$, as also depicted in the sketch of Fig. 4(b).

